

PMPB55ENEA 60 V, N-channel Trench MOSFET 6 June 2016

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm •
- Tin-plated 100 % solderable side pads for optical solder inspection •
- ElectroStatic Discharge (ESD) protection > 2 kV
- AEC-Q101 gualified

3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick	reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	60	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V_{GS} = 10 V; T_{amb} = 25 °C	[1]	-	-	4	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 4 A; T _j = 25 °C		-	42	56	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

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5. Pinning information

Table 2.	Pinning in	formation			
Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	D	drain		D	
2	D	drain			
3	G	gate		G ← ← ↓ ☆ 入	
4	S	source	3 8 4		
5	D	drain	Transparent top view		
6	D	drain	DFN2020MD-6 (SOT1220)	' S	
7	D	drain		017aaa255	
8	S	source			

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PMPB55ENEA	DFN2020MD-6	DFN2020MD-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220		

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMPB55ENEA	2G

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	4	А
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	2.5	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	16	А
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$T_{j(init)}$ = 25 °C; I _D = 1.3 A; DUT in avalanche (unclamped)		-	12.6	mJ
P _{tot} tot	total power dissipation	T _{amb} = 25 °C	[1]	-	1.65	W
		T _{sp} = 25 °C		-	15.6	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	n diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	1.2	А
ESD maximu	um rating				·	
V _{ESD}	electrostatic discharge voltage	НВМ	[2]	-	2000	V

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

[2] Measured between all pins.

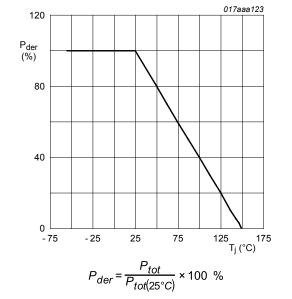
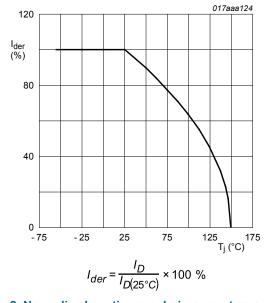


Fig. 1. Normalized total power dissipation as a function of junction temperature

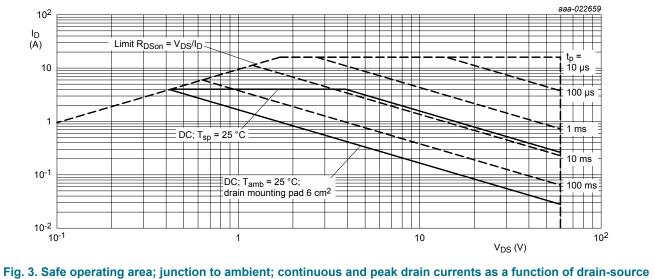




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voltage

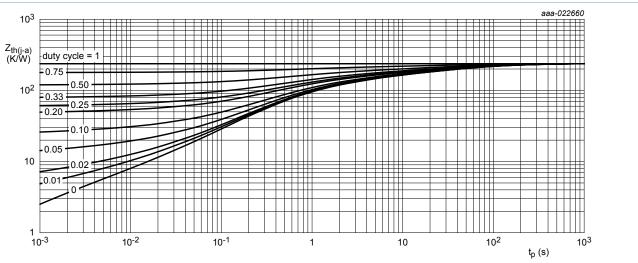
9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	237	273	K/W
			[2]	-	66	76	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	4	8	K/W

Table 6. Thermal characteristics

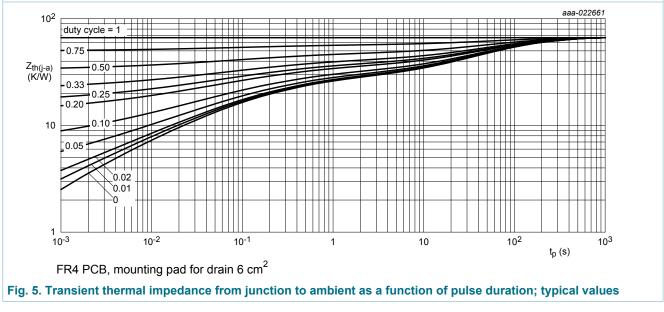
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



FR4 PCB, standard footprint

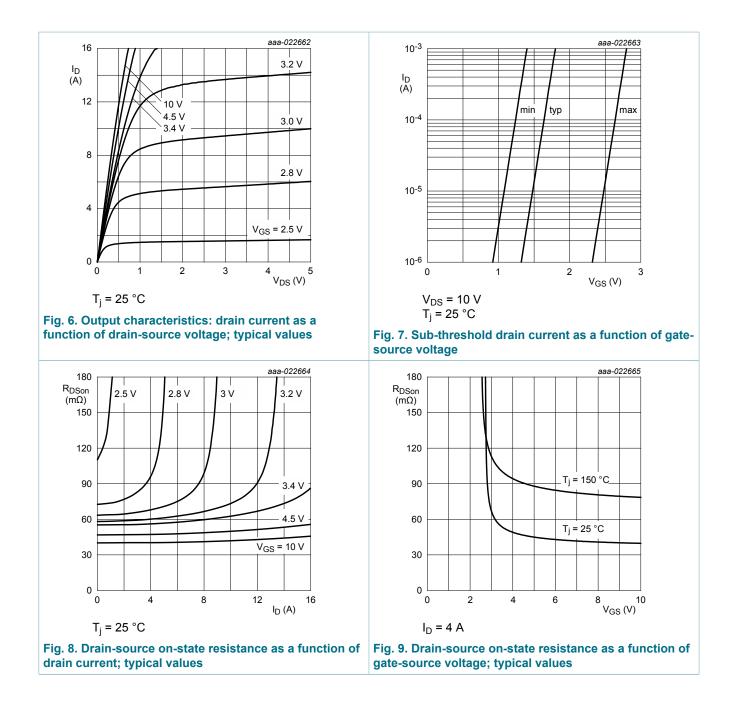




10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	60	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = 250 μA; V _{DS} =V _{GS} ; T _j = 25 °C	1.3	1.7	2.7	V
I _{DSS}	drain leakage current	V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V_{GS} = 10 V; V_{DS} = 0 V; T_j = 25 °C	-	-	1	μA
		V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
R _{DSon} drain-source o	drain-source on-state	V _{GS} = 10 V; I _D = 4 A; T _j = 25 °C	-	42	56	mΩ
resista	resistance	V _{GS} = 10 V; I _D = 4 A; T _j = 150 °C	-	80	106	mΩ
		V _{GS} = 4.5 V; I _D = 3.5 A; T _j = 25 °C	-	48	69	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 4 A; T _j = 25 °C	-	17	-	S
R _G	gate resistance	f = 1 MHz	-	2.7	-	Ω
Dynamic ch	naracteristics	· · · ·				
Q _{G(tot)}	total gate charge	V_{DS} = 30 V; I_{D} = 4 A; V_{GS} = 10 V;	-	7.5	12	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1	-	nC
Q _{GD}	gate-drain charge		-	1.2	-	nC
C _{iss}	input capacitance	V _{DS} = 30 V; f = 1 MHz; V _{GS} = 0 V;	-	435	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	47	-	pF
C _{rss}	reverse transfer capacitance		-	26	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; I_{D} = 4 A; V_{GS} = 10 V;	-	4.5	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	4	-	ns
t _{d(off)}	turn-off delay time		-	13.5	-	ns
t _f	fall time		-	7	-	ns
Source-dra	in diode					
V _{SD}	source-drain voltage	I _S = 1.2 A; V _{GS} = 0 V; T _i = 25 °C	-	0.8	1.2	V

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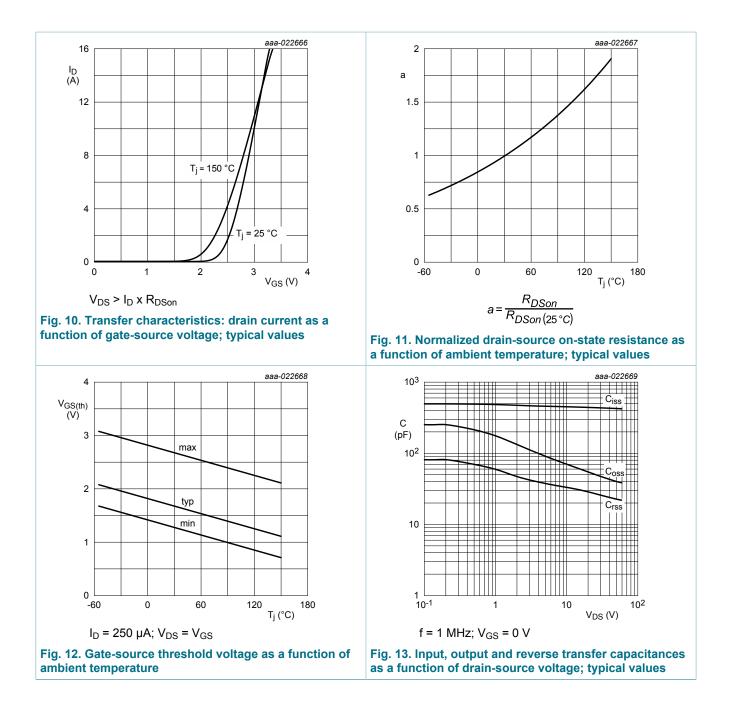


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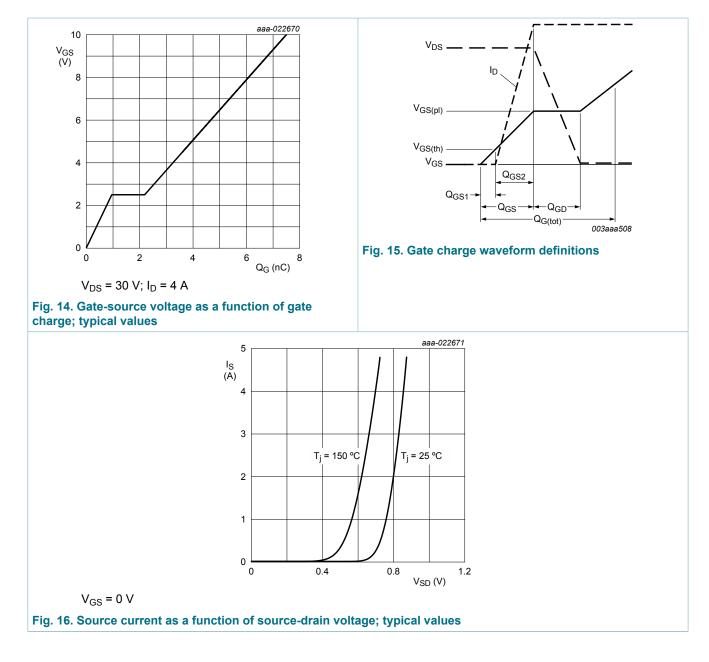
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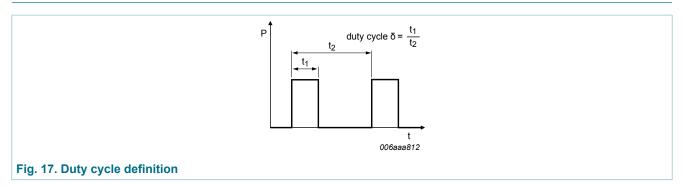
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11. Test information



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Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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12. Package outline

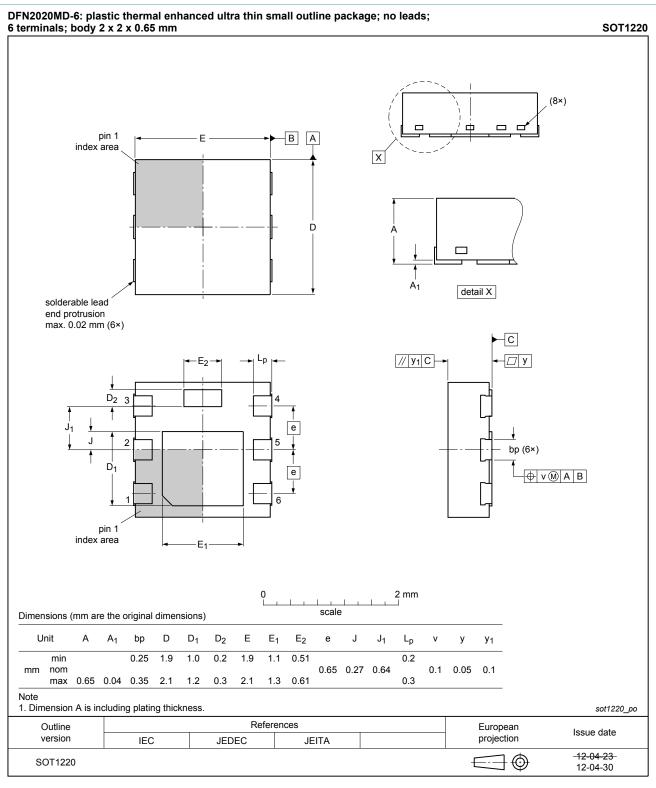
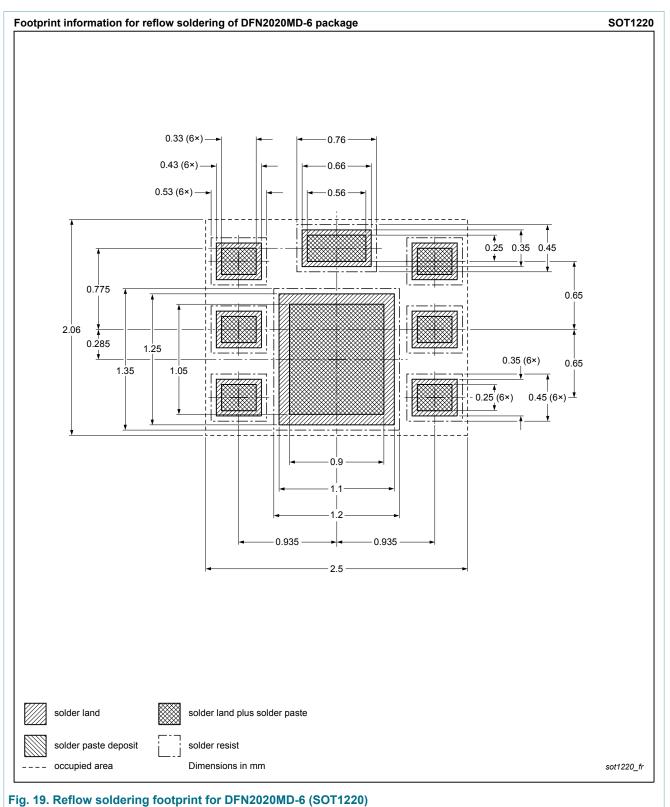


Fig. 18. Package outline DFN2020MD-6 (SOT1220)

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13. Soldering



14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMPB55ENEA v.2	20160606	Product data sheet	-	PMPB55ENEA v.1			
Modifications:	Updated Figure 14						
PMPB55ENEA v.1	20160401	Preliminary data sheet	-	-			

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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